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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(Use as many sheets as necessary)</i>			Application Number		
			Filing Date		
			First Named Inventor	Manchao Xiao	
			Art Unit		
			Examiner Name		
Sheet	1	of	3	Attorney Docket Number	06377ZP USA

U. S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
		US- 6,350,708 B1	02/26/2002	Kelly T. Hurley	
		US- 6,204,206 B1	03/20/2001	Kelly T. Hurley	
		US- 6,127,287	10/03/2000	Kelly T. Hurley, et al	
		US- 5,939,333	08/17/1999	Kelly T. Hurley, et al	
		US- 6,365,231 B2	04/02/2002	Yuusuke Sato, et al	
		US- 6,146,938	11/14/2000	Shigehiko Saida, et al	
		US- 6,284,583 B1	09/04/2001	Shigehiko Saida, et al	
		US- 5,976,991	11/02/1999	Ravi K. Laxman, et al	
		US- 5,234,869	08/10/1993	Yuuichi Mikata, et al	
		US- 5,874,368	02/23/1999	Ravi K. Laxman	
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FOREIGN PATENT DOCUMENTS						
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		Country Code ³ Number ⁴ Kind Code ⁵ (if known)				
		JP 06132284(English abstract)	05/13/1994	Kawasaki Steel Corp		

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NON PATENT LITERATURE DOCUMENTS				
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		G.E. MCGUIRE, Semiconductor Materials and Process Technology Handbook, Noyes Publication, 1988, pp. 289-301.		
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		TETSUJI SORITA, Mass Spectrometric and Kinetic Study of Low-Pressure..., J. Elect. Soc., 1994, Vol. 141, pp. 3505-3511.		
		B.A. SCOTT, Preparation of Silicon Nitride with Good Interface Properties..., Chemtronics, 1989, Vol. 4, pp. 231-234.		
		J.M. GROW, Growth Kinetics and Characterization of Low Pressure..., Elsevier Sci., 1995, Mat. Letters 23, pp. 187-193.		
		W.C. Yeh, Low-Temperature Chemical-Vapor-Deposition of Silicon-Nitride..., J. Appl. Phys., 1996, Vol. 35, pp. 1509-1512.		
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		ROY G. GORDON, Silicon Dimethylamido Complexes and Ammonia..., Chem. Mater. 1990, 2, pp. 480-482.		
		Z.I. SERGEEVA, Synthesis of Alkyl- and Dialkyl-Bis-(1,1-Dialkylhydrazino)-Silanes, J. Gen. Chem. of USSR, 1960, Vol. 30, pp. 716-717.		
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		MARCUS SOLDNER, Isomeric Cyclic Disilanedyl Dimethylhydrazines, Inorg. Chem., 1998, 37, pp. 601-603.		
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		DAVID R. LIDE, Handbook of Chem. and Physics, 81 st Edition, 2001, CRC Press, pp. 9-64-9-69.	

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